NSN 5961-01-633-0083

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-633-0083

Overall Length:
1.449 inches
Overall Width:
0.625 inches
Features Provided:
Very high speed
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Product Name:
Insolated gate bipolar transistor with ultrafast soft recovery diode.
Special Features:
Collector-to-emitter volt 600v max; continuous collector current at 25 degrees celcius is 96 amps; continuous collector current at 100 degrees
celcius is 48 amps; clamp inductive load current 192 amps.
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0